

SK45GH063



SEMITOP® 3

IGBT Module

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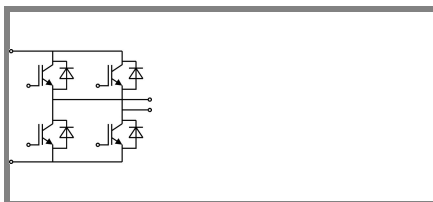
Preliminary Data

Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- N channel, homogeneous Silicon structure (NPT-Non punchthrough IGBT)
- High short circuit capability
- Low tail current with low temperature dependence
- UL recognized, file no. E63532

Typical Applications*

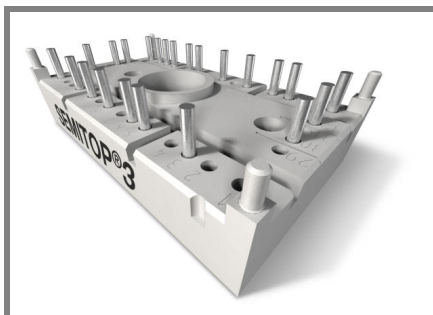
- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS



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Absolute Maximum Ratings		$T_s = 25\text{ }^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	Values			Units
IGBT					
V_{CES}	$T_j = 25\text{ }^\circ\text{C}$	600			V
I_C	$T_j = 125\text{ }^\circ\text{C}$	$T_s = 25\text{ }^\circ\text{C}$	45		A
		$T_s = 80\text{ }^\circ\text{C}$	30		A
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$	100			A
V_{GES}		± 20			V
t_{psc}	$V_{CC} = 300\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125\text{ }^\circ\text{C}$ $V_{CES} < 600\text{ V}$	10			μs
Inverse Diode					
I_F	$T_j = 150\text{ }^\circ\text{C}$	$T_s = 25\text{ }^\circ\text{C}$	57		A
		$T_s = 80\text{ }^\circ\text{C}$	38		A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$	100			A
I_{FSM}	$t_p = 10\text{ ms}; \text{half sine wave } T_j = 150\text{ }^\circ\text{C}$	440			A
Module					
$I_{t(RMS)}$					A
T_{vj}		-40 ... +150			$^\circ\text{C}$
T_{stg}		-40 ... +125			$^\circ\text{C}$
V_{isol}	AC, 1 min.	2500			V

Characteristics		$T_s = 25\text{ }^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 1\text{ mA}$	4,5	5,5	6,5	V
I_{CES}	$V_{GE} = 0\text{ V}, V_{CE} = V_{CES}$	$T_j = 25\text{ }^\circ\text{C}$	0,15		mA
		$T_j = 125\text{ }^\circ\text{C}$			mA
I_{GES}	$V_{CE} = 0\text{ V}, V_{GE} = 30\text{ V}$	$T_j = 25\text{ }^\circ\text{C}$	120		nA
		$T_j = 125\text{ }^\circ\text{C}$			nA
V_{CE0}		$T_j = 25\text{ }^\circ\text{C}$	1		V
		$T_j = 125\text{ }^\circ\text{C}$	1,1		V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ }^\circ\text{C}$	20		$\text{m}\Omega$
		$T_j = 125\text{ }^\circ\text{C}$			$\text{m}\Omega$
$V_{CE(sat)}$	$I_{Cnom} = 50\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25\text{ }^\circ\text{C}_{chiplev.}$	2,1	2,5	V
		$T_j = 125\text{ }^\circ\text{C}_{chiplev.}$			V
C_{ies}	$V_{CE} = 25, V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	2,2		nF
C_{oes}					nF
C_{res}			0,2		nF
Q_G	$V_{GE} = 0 \dots 20\text{ V}$	155			nC
$t_{d(on)}$	$R_{Gon} = 22\ \Omega$	$V_{CC} = 300\text{ V}$ $I_C = 30\text{ A}$	45		ns
t_r			35		ns
E_{on}	$R_{Goff} = 22\ \Omega$	$T_j = 125\text{ }^\circ\text{C}$ $V_{GE} = \pm 15\text{ V}$	1,4		mJ
$t_{d(off)}$			250		ns
t_f			25		ns
E_{off}			1,2		mJ
$R_{th(j-s)}$	per IGBT	1			K/W



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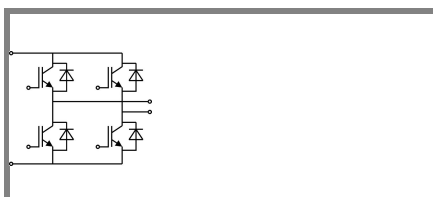
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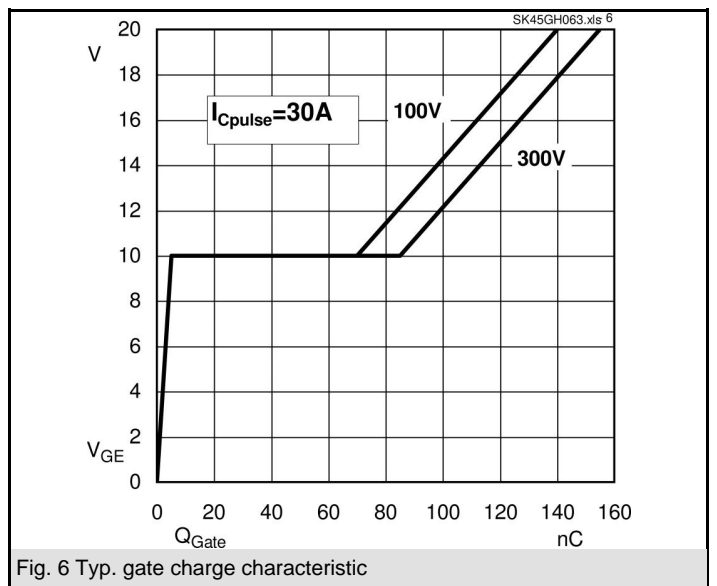
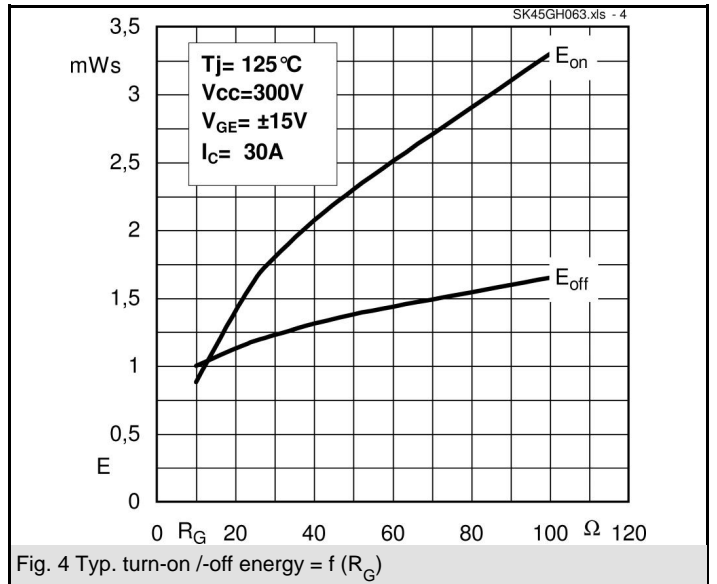
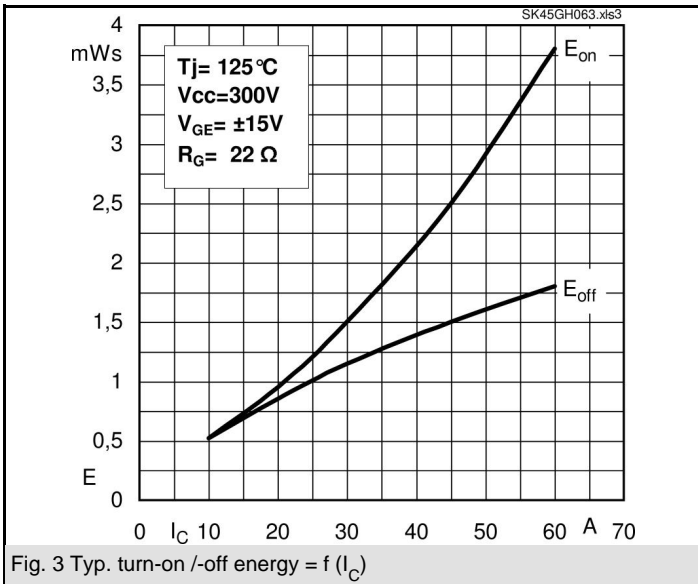
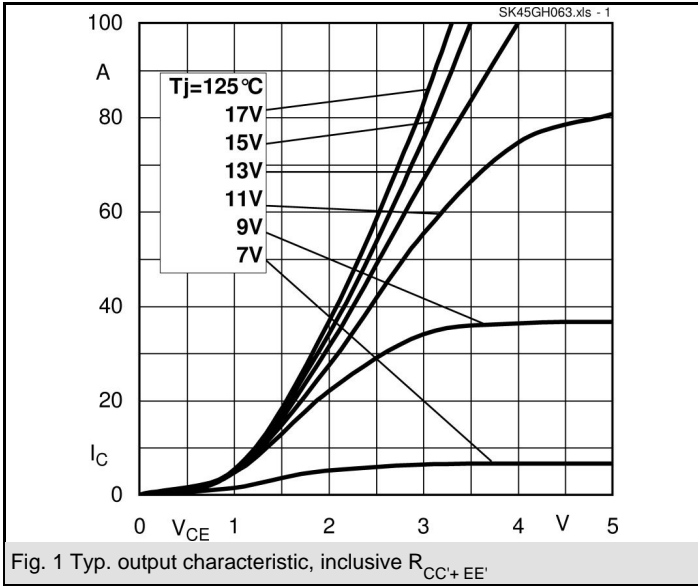
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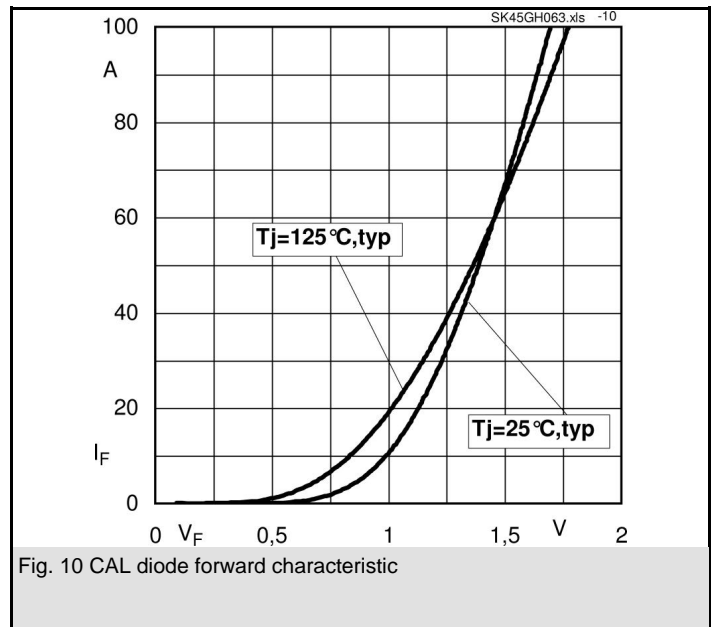
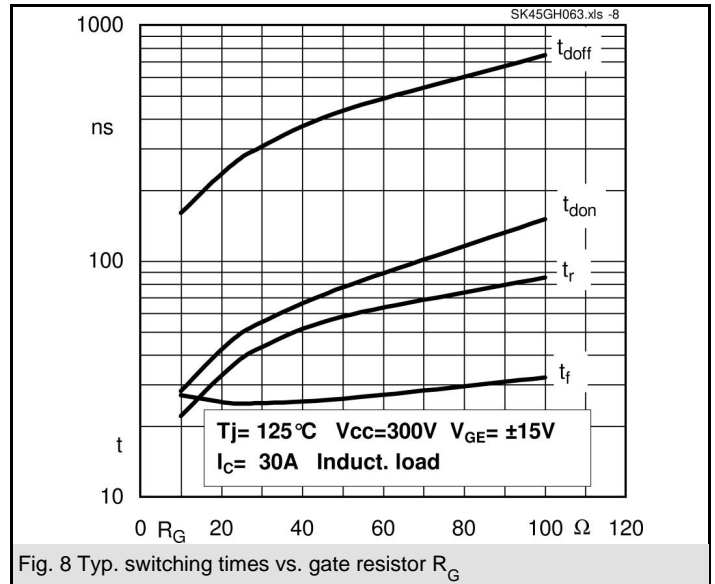
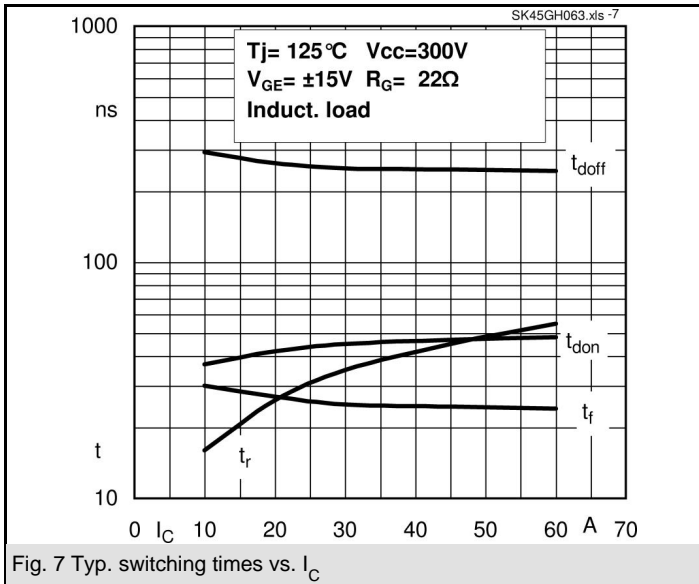
Characteristics

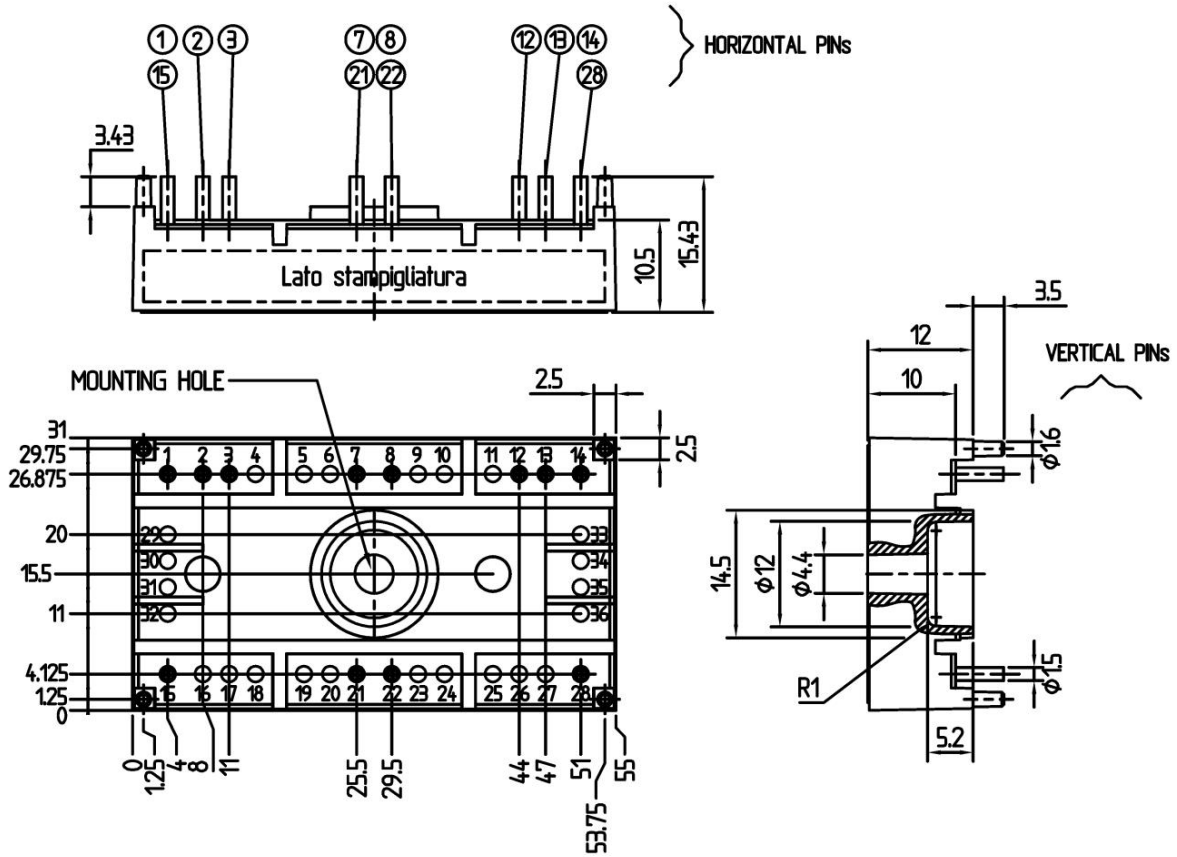
Symbol	Conditions	min.	typ.	max.	Units
Inverse Diode					
$V_F = V_{EC}$	$I_{Fnom} = 30 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}_{chiplev.}$	1,3	1,5	V
		$T_j = 125 \text{ }^\circ\text{C}_{chiplev.}$	1,2	1,45	V
V_{F0}			0,85	0,9	V
r_F			8	16	m Ω
I_{RRM}	$I_F = 30 \text{ A}$		30		A
Q_{rr}	$di/dt = -500 \text{ A}/\mu\text{s}$		3		μC
E_{rr}	$V_{CC} = 300\text{V}$		0,9		mJ
$R_{th(j-s)D}$	per diode			1,2	K/W
M_s	to heat sink M1	2,25		2,5	Nm
w			30		g

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

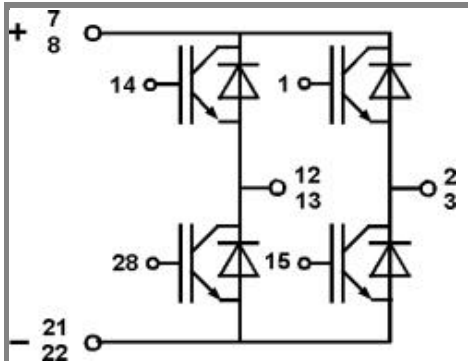
* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.







Case T19 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T 19

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